

5mm Phototransistor

MODEL NO : PT1302B/C2

■ Features :

- Fast response time
- High photo sensitivity
- Axial terminal
- Plastic case with IR filter

■ Description :

- PT1302B/C2 is a high speed and high sensitive silicon NPN phototransistor molder in a standard $\phi 5$ mm package. The package is an IR filter , spectrally mathch to infrared emitter diode.

■ Applications :

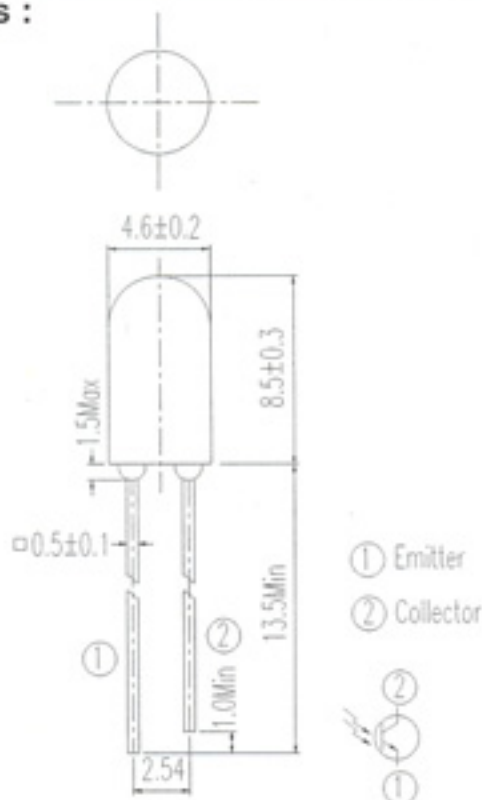
- Optoelectronic switch
- VCRs ,Video camera
- Floppy disk drive
- Infrared applied system

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PT	Silicon	Black

5mm Phototransistor

 MODEL NO : PT1302B/C2

■ Package Dimensions :



■ Notes :

1. All dimensions are in millimeter.
2. Protruded resin under flange 1.5 mm Max.
3. Lead spacing is measured where the lead emerge from the package.
4. Lens color : Black.
5. Above specification may be changed without notice. will reserve authority
on material change for above specification.
6. These specification sheets include materials protected under copyright of corporation . Please don't reproduce or cause anyone to reproduce them without consent.
7. When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. assumes no
responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

5mm Phototransistor

 MODEL NO : PT1302B/C2

■ Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	Notice
Collector-Emitter Voltage	V_{CEO}	30	V	
Emitter-Collector- Voltage	V_{ECO}	5	V	
Collector Current	I_C	20	mA	
Operating Temperature	T_{opr}	$-25 \sim +85$	$^\circ\text{C}$	
Storage Temperature	T_{stg}	$-40 \sim +85$	$^\circ\text{C}$	
Soldering Temperature	T_{sol}	260	$^\circ\text{C}$	4mm from mold body less than 5 seconds
Power Dissipation at(or below) 25 $^\circ\text{C}$ Free Air Temperature	P_c	75	mW	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-Emitter Breakdown Voltage	BV_{CEO}	30	----	----	V	$I_C = 100 \mu\text{A}$ $E_e = 0\text{mW/cm}^2$
Emitter-Collector Breakdown Voltage	BV_{ECO}	5	----	----	V	$I_E = 100 \mu\text{A}$ $E_e = 0\text{mW/cm}^2$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	----	----	0.4	V	$I_C = 2\text{mA}$ $E_e = 1\text{mW/cm}^2$
Rise Time	t_r	----	15	----	μS	$V_{CE} = 5\text{V}$ $I_C = 1\text{mA}$ $R_L = 1000 \Omega$
Fall Time	t_f	----	15	----		
Collector Dark Current	I_{CEO}	----	----	100	nA	$V_{CE} = 20\text{V}$ $E_e = 0\text{mW/cm}^2$
On State Collector Current	$I_{C(on)}$	0.7	1.0	----	mA	$V_{CE} = 5\text{V}$ $E_e = 1\text{mW/cm}^2$
Wavelength of Peak Sensitivity	λ_p	----	980	----	nm	----
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	700---1200	----	nm	----

5mm Phototransistor

 MODEL NO : PT1302B/C2

■ Typical Electrical/Optical/Characteristics Curves

Fig.1 Collector Power Dissipation vs.
Ambient Temperature

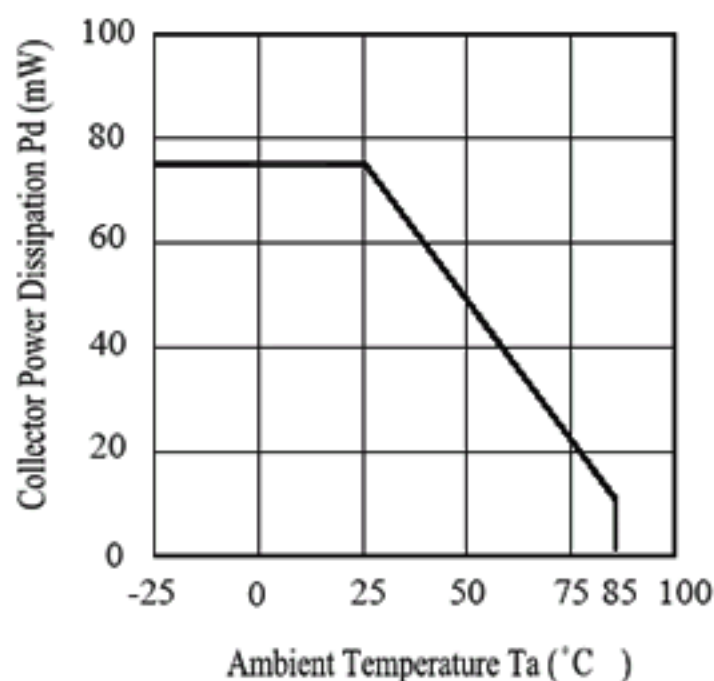


Fig.2 Spectral Sensitivity

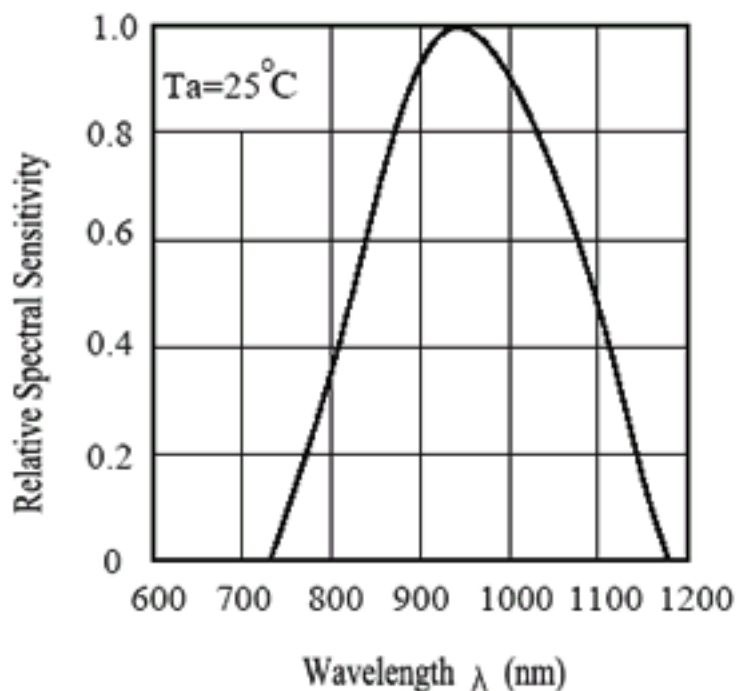


Fig.3 Relative Collector Current vs.
Ambient Temperature

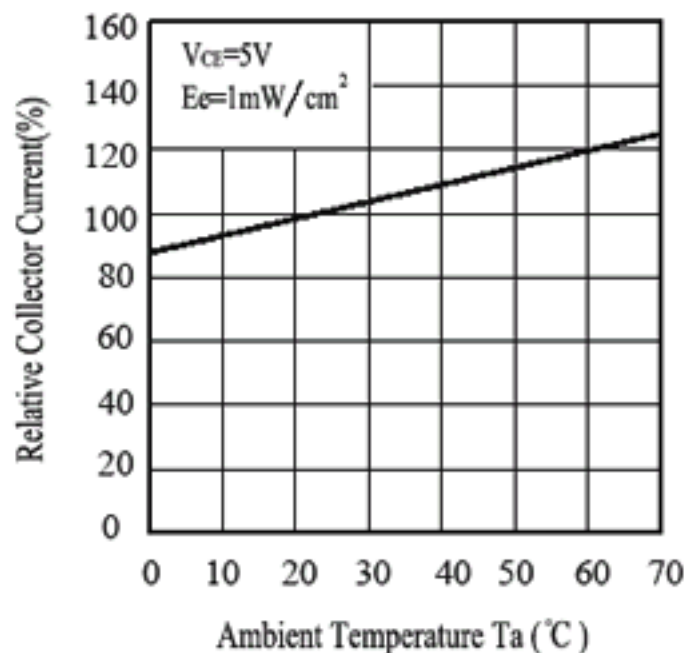


Fig.4 Collector Current vs.
Irradiance

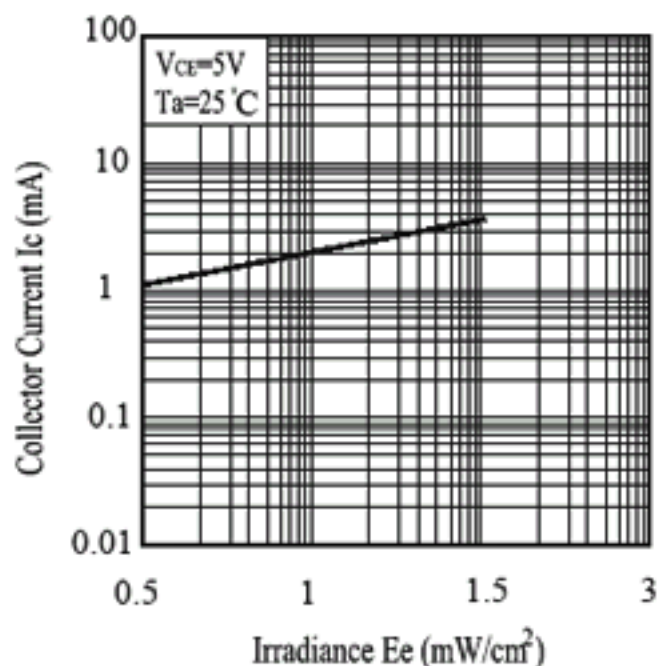


Fig.5 Collector Dark Current vs.
Ambient Temperature

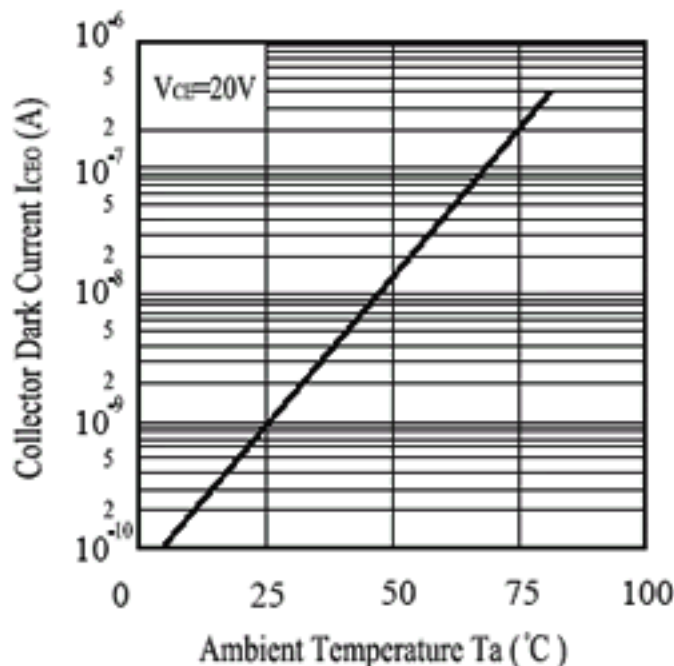
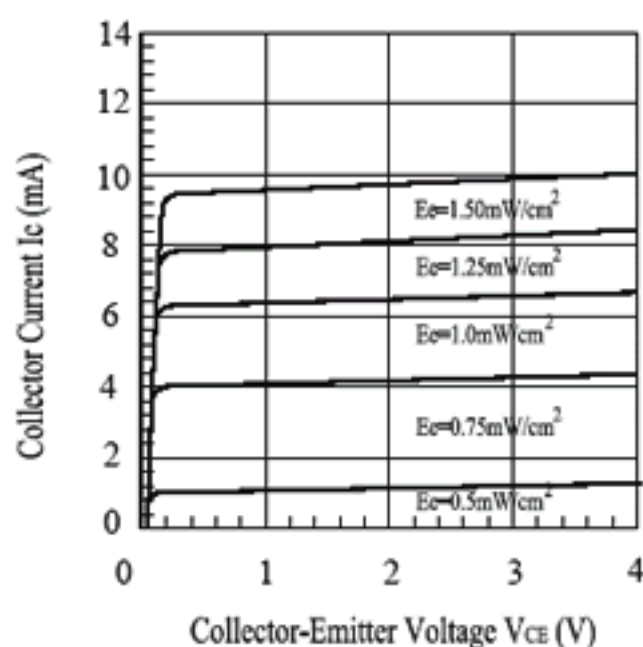


Fig.6 Collector Current vs.
Collector-Emitter Voltage



5mm Phototransistor

 MODEL NO : PT1302B/C2

■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	5 sec	22 PCs	$I_{c(on)} \leq L \times 0.8$ L : Lower specification limit	0/1
2	Temperature Cycle	H : +85°C 30 min $\updownarrow$ 5 min $\updownarrow$ L : -55°C 30 min	50 cycle	22 PCs		0/1
3	Thermal Shock	H : +100°C 5 min $\updownarrow$ 10 sec $\updownarrow$ L : -10°C 30 min	50 cycle	22 PCs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	$V_{CE}=5V$	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

5mm Phototransistor

MODEL NO : PT1302B/C2

■ Test Method For On State Collector Current :

Condition : $E_e=1\text{mW/cm}^2$, $V_{CE}=5\text{V}$ Test Item : Collector Current [$I_{C(on)}$]

Unit : mA

